Hologram Lasers LT0H43M

LT0H43M

■ Features

- With built-in high speed OPIC* (TYP.28MHz) for ×16 speed CD-ROM drive
- (2) Voltage output type(External noise solution is unnecessary.)
- (3) Maximum optical power output: 4.0mW*1
- (4) Wavelength: 780nm
- (5) High temperature operation (MAX. 70°C)

*OPIC: (Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

■ Model No.

(1) LT0H43M....Dual power supply

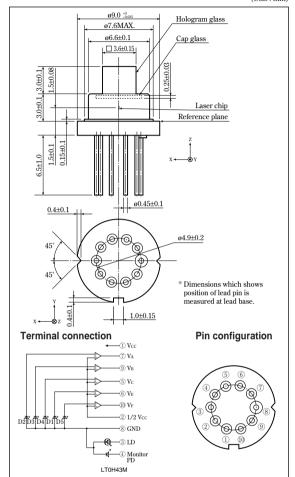
Applications

(1) CD-ROM drives

Hologram Laser for ×16 CD-ROM(3-beam)

Outline Dimensions

(Unit:mm)



Absolute Maximum Ratings

Absolute wax	(Tc=25°C)			
Param	Symbol	Rating	Unit	
*1 Optical power outp	Рн	4.0	mW	
Reverse voltage	Laser	V_R	2	V
	Monitor photodiode	VK	30	V
OPIC supply voltag	Vcc	6	V	
*2 Operating temperat	Topr	-10 to +70	°C	
*2 Storage temperatur	Tstg	-40 to +85	°C	
*3 Soldering temperat	Tsold	260(5s or less)	°C	

^{*1} Output power from hologram laser

^{*2} Case temperature

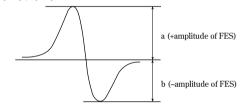
^{*3} At the position of 1.6mm or more from the lead base

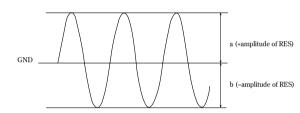
Electro-optical Characteristics

■ Electro-optical Character	istics					(Tc=25°C)
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Focal offset	DEF	$V_{RF}=0.55V$	-0.5	-	+0.5	μm
*2 Focal error symmetry	Bres	$V_{RF}=0.55V$	-20	-	+20	%
*3 Radial error balance	Bres	P _H =3.0mW	-20	-	+20	%
**4 RF output amplitude	$V_{ m RF}$	P _H =3.0mW	0.41	0.90	-	V _{p-p}
*5 FES output amplitude	VFES	Von O FEV	0.23	0.35	0.47	V _{p-p}
	IFES	$V_{ m RF}$ =0.55 V	0.23			
*6 DEC 4 4 114 1	Vres	V _{RF} =0.55V	0.08	0.12	0.16	V _{p-p}
**6 RES output amplitude	Ires					
Threshold current	$\mathbf{I}_{ ext{th}}$	-	-	45	60	mA
Operating current	Iop	P _H =2.5mW	-	55	80	mA
Operating voltage	V_{op}	$P_{H}=2.5mW$	-	1.75	2.5	V
Wavelength	$\lambda_{ m p}$	$P_{H}=2.5mW$	770	780	795	nm
Monitor current	Im	$P_H=2.5mW,V_R=15V$	0.11	0.40	0.88	mA
Differential efficiency	η	1.7mW I(2.5mW)-I(0.8mW)	0.12	0.25	0.52	mW/mA

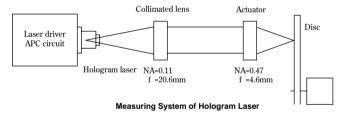
^{*1} Distance between FES=0 and jitter minimum point

2×(a+b) including offset of holgram laser





- **4 Amplitude of Va+VB+2Vc (focal servo ON, radial servo ON)
- *5 V_B–V_A (Focal vibration)
- *6 VE-VF (focal servo ON, radial servo OFF)



Electro-optical Characteristics of Hologram Laser (Design Standard)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Focal dynamic range	Rees	_	-	12	-	μm
*2 FES sensitivity	SFES	-	-	20	-	%/µm
*2 FFS amplitude: 100% Practical value						

Distance between object lens and disc RFES Focal error signal

At the condition of FES sensitivity = 20%/1μ m **2 (a-b) / (a+b)

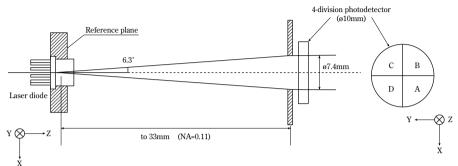
^{*2} FES amplitude: 100%. Practical value

Electro-optical Characteristics of Laser Diode (Design Standard)

(Tc=25°C)

Parai	neter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Radiation	*1 Symmetry	Parallel	SII	Po=3mW,	-25	-	+25	%
characteristics	- Symmeny	Perpendicular	S⊥	into NA=0.11	-15	-	+15	%
			Δx	-	-80	-	+80	μm
Emission point ac	curacy	Position	Δy	1	-80	-	+80	μm
		Δz	-	-80	-	+80	μm	

^{*1} Measuring method of radiation symmetry



Parameter	Definition
sII	$\frac{(P_{\rm B} + P_{\rm C}) - (P_{\rm A} + P_{\rm D})}{Ptotal}$
s⊥	$\frac{(P_A + P_B) - (P_C + P_D)}{Ptotal}$

Px: Output of light detector X

Electrical Characteristics of Monitor Photodiode (Design Standard)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Sensitivity	S	V _R =15V	-	0.16	-	mA/mW
Dark current	$I_{ m d}$	V _R =15V	-	-	150	nA
Terminal capacitance	Ct	V _R =15V	-	3.5	-	pF

^{*1} For hologram output power

Electro-optical Characteristics of OPIC for Signal Detection (Design Standard)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	*1 Segment
Supply voltage	Vcc		4.5	-	5.5	V	
Supply current	Icc	Vcc=5V	2.0	4.5	9.0	mA	
*2 Output off-set voltage	Vod	Vcc=5V, No light	-15	0	+15	mV	Va to VF
Off-set voltage difference	ΔV_{OD}	vcc=3v, No light	-15	0	+15	mV	VA-VB, VE-VF
*3 Response frequency	fcf	**4 -3dB	24	28	-	MHz	Va,VB,Vc
	fcr	-3dB	1.0	2.0	-	MHz	Ve,Vf
Peaking level	V_{PK1}	f=0.1 to 17MHz	-1	0	+1	dB	Va,VB,Vc
	V_{PK2}	f=0.1MHz to	-	-	+2	dB	Va,VB,Vc

^{*1} Applicable divisions correspond to pattern segment No.

 $D\ 5V_F$

^{*2} Difference from Vcc/2

Segment No. output $D\ 1.....V_E$ D 2VA $D\ 3V_B$

^{*3} Output amplitude=0dB(input signal 100kHz) **4 $f_{CF}=(f_{C}(V_{A})+f_{C}(V_{B})+2f_{C}(V_{C}))/4$

D1 D2D4D3D 4Vc D5

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